



### **40V N-CHANNEL ENHANCEMENT MODE MOSFET**

### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>A</sub> = +25°C	
40V	$0.05\Omega$ @ $V_{GS} = 10V$	7A	

### **Description**

This new generation MOSFET has been designed to minimize the onstate resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

# **Applications**

- DC-DC Converters
- Audio Output Stages
- · Relay and Solenoid driving
- Motor Control

### **Features**

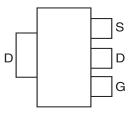
- Low On-Resistance
- Fast Switching Speed
- Low Threshold
- Low Gate Drive
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Available

#### **Mechanical Data**

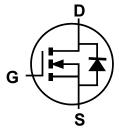
- Case: SOT223
- Case Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper lead frame.
   Solderable per MIL-STD-202, Method 208 <a>®</a>3
- Weight: 0.112 grams (approximate)



Top View



Pin Out - Top View



Equivalent Circuit

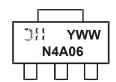
### Ordering Information (Note 4 & 5)

Part Number	Compliance	Case	Packaging
ZXMN4A06GQTA	Automotive	SOT223	1,000/Tape & Reel
ZXMN4A06GQTC	Automotive	SOT223	4,000/Tape & Reel

Note:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_grade\_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



☐ Manufacturer's Marking N4A06 = Marking Code
YWW = Date Code Marking
Y = Year (ex: 3 = 2013)
WW = Week (01 - 53)



# **Maximum Ratings** ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage		$V_{DSS}$	40	V	
Gate-Source Voltage			V <sub>GS</sub>	±20	V
		(Note 7)		7	
Continuous Drain Current	$V_{GS} = 10V$	$T_A = +70^{\circ}C \text{ (Note 7)}$	$I_{D}$	5.6	Α
		(Note 6)		5	
Pulsed Drain Current	V <sub>GS</sub> = 10V	(Note 8)	I <sub>DM</sub>	22	Α
Continuous Source Current (Body diode) (Note 7)		(Note 7)	Is	5.4	Α
Pulsed Source Current (Body diode) (Note 8)		I <sub>SM</sub>	22	Α	

# Thermal Characteristics ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 6)		2 16	W	
Linear Derating Factor	(Note 7)	PD	3.9 31	mW/°C	
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>0JA</sub>	62.5	°C/W	
Thermal Resistance, sunction to Ambient	(Note 7)	NejA	32.2		
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

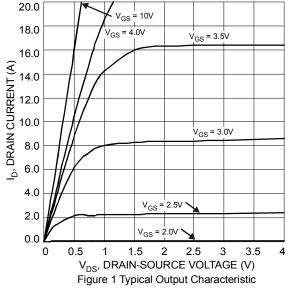
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	40	_	_	V	$I_D = 250 \mu A, V_{GS} = 0 V$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μA	V <sub>DS</sub> = 40V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS							
Gate Threshold Voltage	V <sub>GS(th)</sub>	1			V	$I_D = 250 \mu A, V_{DS} = V_{GS}$	
Static Drain-Source On-Resistance (Note 9)	D			0.05	Ω	V <sub>GS</sub> = 10V, I <sub>D</sub> = 4.5A	
Static Dialit-Source Off-Nesistatice (Note 9)	R <sub>DS(ON)</sub>	_		0.075	32	$V_{GS} = 4.5V$ , $I_D = 3.2A$	
Forward Transconductance (Notes 11)	g <sub>fs</sub>	_	8.7		S	V <sub>DS</sub> = 15V, I <sub>D</sub> = 2.5A	
Diode Forward Voltage (Note 9)	$V_{SD}$	_	0.8	0.95	V	I <sub>S</sub> = 2.5A, V <sub>GS</sub> = 0V, T <sub>J</sub> = +25°C	
Reverse recovery time (Note 11)	t <sub>rr</sub>		14.5	_	ns	$I_F = 2.5A$ , di/dt = 100A/ $\mu$ s, $T_J = +25$ °C	
Reverse recovery charge (Note 11)	Q <sub>rr</sub>	_	7.8	_	nC		
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C <sub>iss</sub>	_	746	_	pF	V <sub>DS</sub> = 40V, V <sub>GS</sub> = 0V f = 1MHz	
Output Capacitance	Coss	_	93		pF		
Reverse Transfer Capacitance	C <sub>rss</sub>	_	60	_	pF	1 - 1101112	
Total Gate Charge (Note 11)	$Q_g$	_	19	_	nC	V 00V V 40V	
Gate-Source Charge (Note 11)	$Q_{gs}$	_	2.3	_	nC	$V_{DS}$ = 30V, $V_{GS}$ = 10V, $I_{D}$ = 2.5A (refer to test circuit)	
Gate-Drain Charge (Note 11)	$Q_{gd}$	_	4.1	_	nC		
Turn-On Delay Time (Note 11)	t <sub>D(on)</sub>	_	3.4	_	ns	$V_{DD}$ = 30V, $V_{GS}$ = 10V $I_{D}$ = 2.5A, $R_{G} \cong 6\Omega$ (refer to test circuit)	
Turn-On Rise Time (Note 11)	t <sub>r</sub>	_	2.8	_	ns		
Turn-Off Delay Time (Note 11)	t <sub>D(off)</sub>	_	20	_	ns		
Turn-Off Fall Time (Note 11)	t <sub>f</sub>	_	7.7	_	ns		

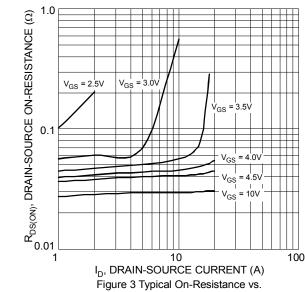
Notes:

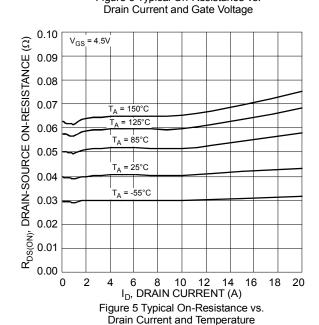
- 6. For a device surface mounted on 25mm x 25mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions. 7. For a device surface mounted on FR-4 PCB measured at t≤5 secs. 8. Repetitive rating 25mm x 25mm FR4 PCB, D = 0.05, pulse width 10µs pulse width limited by maximum junction temperature.

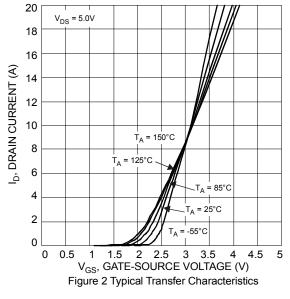
- 9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s; duty cycle  $\leq$  2%.
- 10. Switching characteristics are independent of operating junction temperatures.
- 11. For design aid only, not subject to production testing.

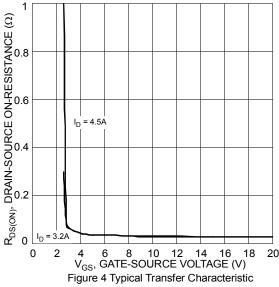


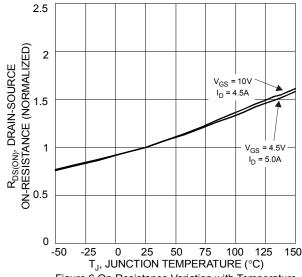














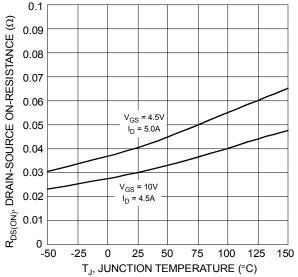
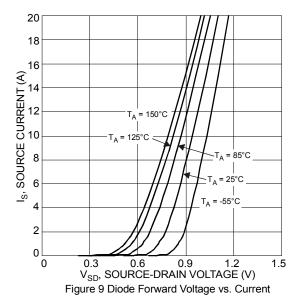
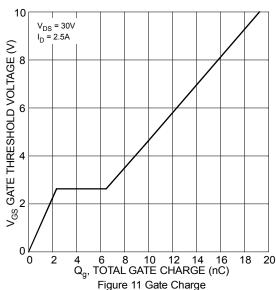
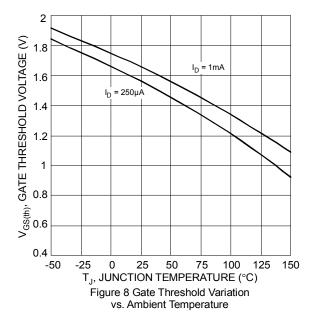
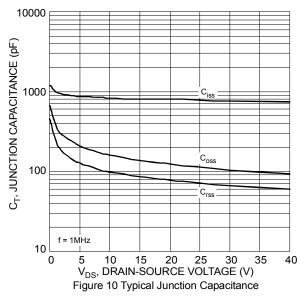


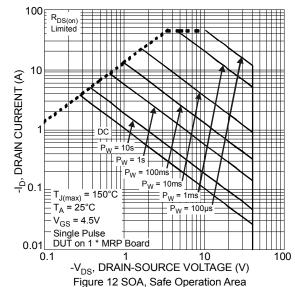
Figure 7 On-Resistance Variation with Temperature



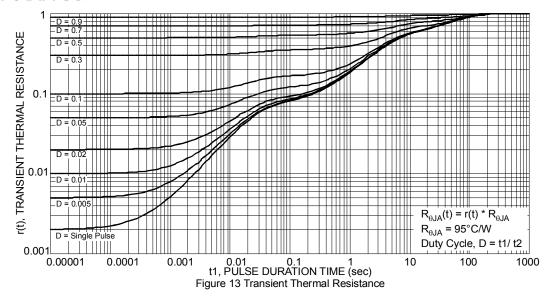






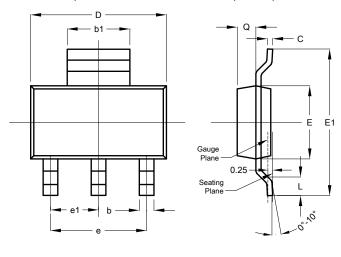




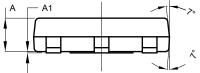


## **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

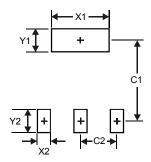


SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b1	2.90	3.10	3.00		
b2	0.60	0.80	0.70		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	_	-	4.60		
e1			2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					



# **Suggested Pad Layout**

 $Please see AP02001 \ at \ http://www.diodes.com/datasheets/ap02001.pdf \ for \ latest \ version.$ 



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3



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